**FEATURES**

- 12A Output Current
- Wide $V_{IN}$ Range = 4V to 24V
- Internal N-Channel MOSFETs
- True Current Mode Control
- Optimized for High Step-Down Ratios
- $I_{ON(MIN)} \leq 100\text{ns}$
- Extremely Fast Transient Response
- Stable with Ceramic $C_{OUT}$
- $\pm 1\%$ 0.6V Voltage Reference
- Power Good Output Voltage Monitor
- Adjustable On-Time/Switching Frequency
- Adjustable Current Limit
- Programmable Soft-Start
- Output Overvoltage Protection
- Optional Short-Circuit Shutdown Timer
- Low Shutdown $I_Q$: 15\,$\mu\text{A}$
- Available in a 9mm $\times$ 9mm 64-Pin QFN Package

**APPLICATIONS**

- Point of Load Regulation
- Distributed Power Systems

---

**DESCRIPTION**

The LTC3610 is a high efficiency, monolithic synchronous step-down DC/DC converter that can deliver up to 12A output current from a 4V to 24V (28V maximum) input supply. It uses a valley current control architecture to deliver very low duty cycle operation at high frequency with excellent transient response. The operating frequency is selected by an external resistor and is compensated for variations in $V_{IN}$ and $V_{OUT}$.

The LTC3610 can be configured for discontinuous or forced continuous operation at light load. Forced continuous operation reduces noise and RF interference while discontinuous mode provides high efficiency by reducing switching losses at light loads.

Fault protection is provided by internal foldback current limiting, an output overvoltage comparator and an optional short-circuit shutdown timer. Soft-start capability for supply sequencing is accomplished using an external timing capacitor. The regulator current limit is user programmable.

A power good output voltage monitor indicates when the output is in regulation. The LTC3610 is available in a compact 9mm $\times$ 9mm QFN package.

---

**TYPICAL APPLICATION**

High Efficiency Step-Down Converter

![High Efficiency Step-Down Converter Diagram](image)

**Efficiency vs Load Current**

![Efficiency vs Load Current Graph](image)
**Absolute Maximum Ratings**

(Note 1)

Input Supply Voltage (VIN, ION) .................. 28V to –0.3V

Boosted Topside Driver Supply Voltage

(BOOST) ........................................ 34V to –0.3V

SW Voltage ........................................ 28V to –0.3V

INTVCC, EXTVCC, (BOOST – SW), RUN/SS,

PGOOD Voltages ................................ 7V to –0.3V

FCB, VON, VRNG Voltages ....................... INTVCC + 0.3V to –0.3V

IITH, VFB Voltages ................................ 2.7V to –0.3V

Operating Temperature Range

(Note 4) ........................................ –40°C to 125°C

Junction Temperature (Note 2) ..................... 125°C

Storage Temperature Range ..................... –55°C to 125°C

**Order Information**

**LEAD FREE FINISH**

<table>
<thead>
<tr>
<th>PART NUMBER</th>
<th>TAPE AND REEL</th>
<th>PART MARKING*</th>
<th>PACKAGE DESCRIPTION</th>
<th>TEMPERATURE RANGE</th>
</tr>
</thead>
<tbody>
<tr>
<td>LTC3610EWP#PBF</td>
<td>LTC3610EWP#TRPBF</td>
<td>LTC3610WP</td>
<td>64-Lead (9mm x 9mm) Plastic QFN</td>
<td>–40°C to 125°C</td>
</tr>
<tr>
<td>LTC3610IWP#PBF</td>
<td>LTC3610IWP#TRPBF</td>
<td>LTC3610WP</td>
<td>64-Lead (9mm x 9mm) Plastic QFN</td>
<td>–40°C to 125°C</td>
</tr>
</tbody>
</table>

**LEAD BASED FINISH**

<table>
<thead>
<tr>
<th>PART NUMBER</th>
<th>TAPE AND REEL</th>
<th>PART MARKING*</th>
<th>PACKAGE DESCRIPTION</th>
<th>TEMPERATURE RANGE</th>
</tr>
</thead>
<tbody>
<tr>
<td>LTC3610EWP</td>
<td>LTC3610EWP#TR</td>
<td>LTC3610WP</td>
<td>64-Lead (9mm x 9mm) Plastic QFN</td>
<td>–40°C to 125°C</td>
</tr>
<tr>
<td>LTC3610IWP</td>
<td>LTC3610IWP#TR</td>
<td>LTC3610WP</td>
<td>64-Lead (9mm x 9mm) Plastic QFN</td>
<td>–40°C to 125°C</td>
</tr>
</tbody>
</table>

Consult LTC Marketing for parts specified with wider operating temperature ranges. *The temperature grade is identified by a label on the shipping container.

For more information on lead free part marking, go to: http://www.linear.com/leadfree/

For more information on tape and reel specifications, go to: http://www.linear.com/tapeandreel/

**Electrical Characteristics**

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at TA = 25°C (Note 4). VIN = 15V unless otherwise noted.

<table>
<thead>
<tr>
<th>SYMBOL</th>
<th>PARAMETER</th>
<th>CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNITS</th>
</tr>
</thead>
<tbody>
<tr>
<td>VIN</td>
<td>Operating Input Voltage Range</td>
<td></td>
<td>4</td>
<td>24</td>
<td></td>
<td>V</td>
</tr>
</tbody>
</table>
| IQ     | Input DC Supply Current
       | Normal Supply Current | | 900 | 2000| 30  | μA    |
| VFB    | Feedback Reference Voltage
       | ITH = 1.2V (Note 3) | | 0.594 | 0.600 | 0.606 | V |
| ΔVFB(LINEREG) | Feedback Voltage Line Regulation
       | VIN = 4V to 28V, ITH = 1.2V (Note 3) | | 0.002 |     |     | %/V   |
# Electrical Characteristics

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$ (Note 4). $V_{IN} = 15\text{V}$ unless otherwise noted.

<table>
<thead>
<tr>
<th>SYMBOL</th>
<th>PARAMETER</th>
<th>CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNITS</th>
</tr>
</thead>
<tbody>
<tr>
<td>$\Delta V_{FB(LOADREG)}$</td>
<td>Feedback Voltage Load Regulation</td>
<td>$I_{TH} = 0.5\text{V}$ to $1.9\text{V}$ (Note 3)</td>
<td>−0.05</td>
<td>−0.3</td>
<td></td>
<td>%</td>
</tr>
<tr>
<td>$I_{FB}$</td>
<td>Feedback Input Current</td>
<td>$V_{FB} = 0.6\text{V}$</td>
<td>−5</td>
<td>±50</td>
<td></td>
<td>nA</td>
</tr>
<tr>
<td>$g_m(\text{EA})$</td>
<td>Error Amplifier Transconductance</td>
<td>$I_{TH} = 1.2\text{V}$ (Note 3)</td>
<td></td>
<td>1.4</td>
<td>1.7</td>
<td>mS</td>
</tr>
<tr>
<td>$V_{FCB}$</td>
<td>Forced Continuous Threshold</td>
<td>●</td>
<td>0.54</td>
<td>0.6</td>
<td>0.66</td>
<td>V</td>
</tr>
<tr>
<td>$I_{FCB}$</td>
<td>Forced Continuous Pin Current</td>
<td>$V_{FCB} = 0.6\text{V}$</td>
<td>−1</td>
<td>−2</td>
<td></td>
<td>µA</td>
</tr>
<tr>
<td>$I_{ON}$</td>
<td>On-Time</td>
<td>$I_{ON} = 180\mu\text{A}$, $V_{ON} = 0\text{V}$</td>
<td>170</td>
<td>250</td>
<td>310</td>
<td>ns</td>
</tr>
<tr>
<td>$I_{ON(MIN)}$</td>
<td>Minimum On-Time</td>
<td>$I_{ON} = 60\mu\text{A}$, $V_{ON} = 0\text{V}$</td>
<td>60</td>
<td>100</td>
<td></td>
<td>ns</td>
</tr>
<tr>
<td>$I_{OFF(MIN)}$</td>
<td>Minimum Off-Time</td>
<td>$I_{ON} = 30\mu\text{A}$, $V_{ON} = 1.5\text{V}$</td>
<td>290</td>
<td>500</td>
<td></td>
<td>ns</td>
</tr>
<tr>
<td>$I_{VOLLEY(MAX)}$</td>
<td>Maximum Valley Current</td>
<td>$V_{RING} = 0.5\text{V}$, $V_{FB} = 0.56\text{V}$, $F_{CB} = 0\text{V}$</td>
<td>7</td>
<td>16</td>
<td></td>
<td>A</td>
</tr>
<tr>
<td>$I_{VOLLEY(MIN)}$</td>
<td>Maximum Reverse Valley Current</td>
<td>$V_{RING} = 0.5\text{V}$, $V_{FB} = 0.64\text{V}$, $F_{CB} = 0\text{V}$</td>
<td>−6</td>
<td>−9</td>
<td></td>
<td>A</td>
</tr>
<tr>
<td>$\Delta V_{FB(OV)}$</td>
<td>Output Overvoltage Fault Threshold</td>
<td>●</td>
<td>7</td>
<td>10</td>
<td>13</td>
<td>%</td>
</tr>
<tr>
<td>$V_{RUN/SS(ON)}$</td>
<td>RUN Pin Start Threshold</td>
<td>●</td>
<td>0.8</td>
<td>1.5</td>
<td>2</td>
<td>V</td>
</tr>
<tr>
<td>$V_{RUN/SS(LE)}$</td>
<td>RUN Pin Latchoff Enable Threshold</td>
<td>RUN/SS Pin Rising</td>
<td>4</td>
<td>4.5</td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>$V_{RUN/SS(LT)}$</td>
<td>RUN Pin Latchoff Threshold</td>
<td>RUN/SS Pin Falling</td>
<td>3.5</td>
<td>4.2</td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>$I_{RUN/SS(C)}$</td>
<td>Soft-Start Charge Current</td>
<td>$V_{RUN/SS} = 0\text{V}$</td>
<td>−0.5</td>
<td>−1.2</td>
<td>−3</td>
<td>µA</td>
</tr>
<tr>
<td>$I_{RUN/SS(D)}$</td>
<td>Soft-Start Discharge Current</td>
<td>$V_{RUN/SS} = 4.5\text{V}$, $V_{FB} = 0\text{V}$</td>
<td>0.8</td>
<td>1.8</td>
<td>3</td>
<td>µA</td>
</tr>
<tr>
<td>$V_{IN(UVLOR)}$</td>
<td>Undervoltage Lockout Release</td>
<td>$V_{IN}$ Falling</td>
<td>3.4</td>
<td>3.9</td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>$R_{DS(ON)}$</td>
<td>Top Switch On-Resistance</td>
<td>Bottom Switch On-Resistance</td>
<td>12</td>
<td>16</td>
<td></td>
<td>mΩ</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>6.5</td>
<td>10</td>
<td></td>
<td>mΩ</td>
</tr>
</tbody>
</table>

## Internal $V_{CC}$ Regulator

<table>
<thead>
<tr>
<th>SYMBOL</th>
<th>PARAMETER</th>
<th>CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNITS</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_{IN\text{TVCC}}$</td>
<td>Internal $V_{CC}$ Voltage</td>
<td>$6V &lt; V_{IN} &lt; 28V$, $V_{EXTVCC} = 4V$</td>
<td>●</td>
<td>4.7</td>
<td>5.5</td>
<td>V</td>
</tr>
<tr>
<td>$\Delta V_{LDD(LOADREG)}$</td>
<td>Internal $V_{CC}$ Load Regulation</td>
<td>$I_{CC} = 0\text{mA}$ to $20\text{mA}$, $V_{EXTVCC} = 4V$</td>
<td>−0.1</td>
<td>±2</td>
<td></td>
<td>%</td>
</tr>
<tr>
<td>$V_{EXTVCC}$</td>
<td>EXTVCC Switchover Voltage</td>
<td>$I_{CC} = 20\text{mA}$, $V_{EXTVCC}$ Rising</td>
<td>●</td>
<td>4.5</td>
<td>4.7</td>
<td>V</td>
</tr>
<tr>
<td>$\Delta V_{EXTVCC}$</td>
<td>EXTVCC Switch Drop Voltage</td>
<td>$I_{CC} = 20\text{mA}$, $V_{EXTVCC} = 5V$</td>
<td>150</td>
<td>300</td>
<td></td>
<td>mV</td>
</tr>
<tr>
<td>$\Delta V_{EXTVCC(HYS)}$</td>
<td>EXTVCC Switcher Hysteresis</td>
<td></td>
<td>500</td>
<td></td>
<td></td>
<td>mV</td>
</tr>
</tbody>
</table>

## PGOOD Output

<table>
<thead>
<tr>
<th>SYMBOL</th>
<th>PARAMETER</th>
<th>CONDITIONS</th>
</tr>
</thead>
<tbody>
<tr>
<td>$\Delta V_{FBH}$</td>
<td>PGOOD Upper Threshold</td>
<td>$V_{FB}$ Rising</td>
</tr>
<tr>
<td>$\Delta V_{FL}$</td>
<td>PGOOD Lower Threshold</td>
<td>$V_{FB}$ Falling</td>
</tr>
<tr>
<td>$V_{FB(HYS)}$</td>
<td>PGOOD Hysteresis</td>
<td>$V_{FB}$ Returning</td>
</tr>
<tr>
<td>$V_{PGL}$</td>
<td>PGOOD Low Voltage</td>
<td>$I_{PGOOD} = 5\text{mA}$</td>
</tr>
</tbody>
</table>

### Notes

1. Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

2. $T_j$ is calculated from the ambient temperature $T_A$ and power dissipation $P_D$ as follows:

$$T_j = T_A + (P_D \times 28^\circ\text{C/W})$$

3. $\theta JA$ is simulated per JESD51-7 high effective thermal conductivity test board

4. $\theta JC$ is simulated when heat sink is applied at the bottom of the package.

### Note 3: The LTC3610 is tested in a feedback loop that adjusts $V_{FB}$ to achieve a specified error amplifier output voltage ($I_{TH}$).

### Note 4: The LTC3610 is tested under pulsed load conditions such that $T_j = T_A$. The LTC3610E is guaranteed to meet performance specifications from $0^\circ\text{C}$ to $125^\circ\text{C}$. Specifications over the $−40^\circ\text{C}$ to $125^\circ\text{C}$ operating temperature range are assured by design, characterization and correlation with statistical process controls. The LTC3610I is guaranteed over the full $−40^\circ\text{C}$ to $125^\circ\text{C}$ operating junction temperature range. Note that the maximum ambient temperature is determined by specific operating conditions in conjunction with board layout, the rated package thermal resistance and other environmental factors.
TYPICAL PERFORMANCE CHARACTERISTICS

**Efficiency vs Load Current**
- **Discontinuous Mode**
- **Continuous Mode**
- Load Current (A): 0.001 to 1A

**Efficiency vs Input Voltage**
- FCB = 0V
- Input Voltage (V): 5V to 25V

**Frequency vs Input Voltage**
- ILOAD = 1A to 10A
- Input Voltage (V): 5V to 25V

**Frequency vs Load Current**
- Load Current (A): 0 to 12A

**Load Regulation**
- ILOAD = 1A to 7A
- Load Current (A): 0 to 12A

**IOUT Voltage vs Load Current**
- Load Current (A): 0 to 12A

**Transient Response**
- **Discontinuous Mode**
- Load Step 0A to 8A
- VIN = 12V
- VOUT = 2.5V

**Start-Up**
- VIN = 12V
- VOUT = 2.5V
- RLOAD = 0.5Ω

**Figure 6 Circuit**
- LTC3610
- 40µs/DIV
- 100mV/DIV
- 5A/DIV
TYPICAL PERFORMANCE CHARACTERISTICS

Load Current vs $I_{TH}$ Voltage and $V_{RNG}$

On-Time vs $I_{ON}$ Current

On-Time vs $V_{ON}$ Voltage

On-Time vs Temperature

Maximum Valley Current Limit vs $V_{RNG}$ Voltage

Maximum Valley Current Limit vs RUN/SS Voltage

Maximum Valley Current Limit vs Temperature

Input Voltage vs Maximum Valley Current

Maximum Valley Current Limit in Foldback
TYPICAL PERFORMANCE CHARACTERISTICS

Feedback Reference Voltage vs Temperature

Error Amplifier $g_m$ vs Temperature

Input and Shutdown Currents vs Input Voltage

INTVCC Load Regulation

$I_{EXTVCC}$ vs Frequency

EXTVCC Switch Resistance vs Temperature

RUN/SS Pin Current vs Temperature

RUN/SS Pin Current vs Temperature

Undervoltage Lockout Threshold vs Temperature
**PIN FUNCTIONS**

**PGND (Pins 1, 2, 3, 56, 57, 58, 59, 60, 61, 62, 63, 64, 65):** Power Ground. Connect this pin closely to the (–) terminal of CVCC and the (–) terminal of CIN.

**SW (Pins 4, 5, 6, 7, 8, 9, 10, 11, 26, 55, 66):** Switch Node Connection to the Inductor. The (–) terminal of the bootstrap capacitor CB also connects here. This pin swings from a diode voltage drop below ground up to VIN.

**PVIN (Pins 12, 13, 14, 15, 16, 17, 18, 19, 20, 21, 22, 23, 24, 25, 67):** Main Input Supply. Decouple this pin to power PGND with the input capacitance CIN.

**NC (Pin 27):** No Connection.

**SGND (Pins 28, 31, 32, 33, 34, 40, 42, 45, 46, 47, 48, 49, 50, 68):** Signal Ground. All small-signal components and compensation components should connect to this ground, which in turn connects to PGND at one point.

**BOOST (Pin 29):** Boosted Floating Driver Supply. The (+) terminal of the bootstrap capacitor CB connects here. This pin swings from a diode voltage drop below INTVCC up to VIN + INTVCC.

**RUN/SS (Pin 30):** Run Control and Soft-Start Input. A capacitor to ground at this pin sets the ramp time to full output current (approximately 3s/µF) and the time delay for overcurrent latchoff (see Applications Information). Forcing this pin below 0.8V shuts down the device.

**VON (Pin 35):** On-Time Voltage Input. Voltage trip point for the on-time comparator. Tying this pin to the output voltage or an external resistive divider from the output makes the on-time proportional to VOUT. The comparator input defaults to 0.7V when the pin is grounded and defaults to 2.4V when the pin is tied to INTVCC. Tie this pin to INTVCC in high VOUT applications to use a lower RON value.

**VRNG (Pin 37):** Current Limit Range Input. The voltage at this pin adjusts maximum valley current and can be set from 0.5V to 0.7V by a resistive divider from INTVCC. It defaults to 0.7V if the VRNG pin is tied to ground which results in a typical 19A current limit.

**ITH (Pin 38):** Current Control Threshold and Error Amplifier Compensation Point. The current comparator threshold increases with this control voltage. The voltage ranges from 0V to 2.4V with 0.8V corresponding to zero sense voltage (zero current).

**FCB (Pin 39):** Forced Continuous Input. Tie this pin to ground to force continuous synchronous operation at low load, to INTVCC to enable discontinuous mode operation at low load or to a resistive divider from a secondary output when using a secondary winding.

**ION (Pin 41):** On-Time Current Input. Tie a resistor from VIN to this pin to set the one-shot timer current and thereby set the switching frequency.

**VFB (Pin 43):** Error Amplifier Feedback Input. This pin connects the error amplifier input to an external resistive divider from VOUT.

**EXTVCC (Pin 44):** External VCC Input. When EXTVCC exceeds 4.7V, an internal switch connects this pin to INTVCC and shuts down the internal regulator so that controller and gate drive power is drawn from EXTVCC. Do not exceed 7V at this pin and ensure that EXTVCC < VIN.

**SVIN (Pins 51, 52):** Supply Pin for Internal PWM Controller.

**INTVCC (Pins 53, 54):** Internal 5V Regulator Output. The driver and control circuits are powered from this voltage. Decouple this pin to power ground with a minimum of 4.7µF low ESR tantalum or ceramic capacitor.
**OPERATION**

**Main Control Loop**

The LTC3610 is a high efficiency monolithic synchronous, step-down DC/DC converter utilizing a constant on-time, current mode architecture. It operates from an input voltage range of 4V to 24V and provides a regulated output voltage at up to 12A of output current. The internal synchronous power switch increases efficiency and eliminates the need for an external Schottky diode. In normal operation, the top MOSFET is turned on for a fixed interval determined by a one-shot timer \( OST \). When the top MOSFET is turned off, the bottom MOSFET is turned on until the current comparator \( I_{\text{CMP}} \) trips, restarting the one-shot timer and initiating the next cycle. Inductor current is determined by sensing the voltage between the PGND and SW pins using the bottom MOSFET on-resistance. The voltage on the \( I_{\text{TH}} \) pin sets the comparator threshold corresponding to inductor valley current. The error amplifier, EA, adjusts this voltage by comparing the feedback signal \( V_{FB} \) from the output voltage with an internal 0.6V reference. If the load current increases, it causes a drop in the feedback voltage relative to the reference. The \( I_{\text{TH}} \) voltage then rises until the average inductor current again matches the load current.

At light load, the inductor current can drop to zero and become negative. This is detected by current reversal comparator \( I_{\text{REV}} \) which then shuts off M2 (see Functional Diagram), resulting in discontinuous operation. Both switches will remain off with the output capacitor supplying the load current until the \( I_{\text{TH}} \) voltage rises above the zero current level (0.8V) to initiate another cycle. Discontinuous mode operation is disabled by comparator F when the FCB pin is brought below 0.6V, forcing continuous synchronous operation.

The operating frequency is determined implicitly by the top MOSFET on-time and the duty cycle required to maintain regulation. The one-shot timer generates an on-time that is proportional to the ideal duty cycle, thus holding frequency approximately constant with changes in \( V_{IN} \). The nominal frequency can be adjusted with an external resistor, \( R_{ON} \).

Overvoltage and undervoltage comparators \( OV \) and \( UV \) pull the PGOOD output low if the output feedback voltage exits a ±10% window around the regulation point. Furthermore, in an overvoltage condition, M1 is turned off and M2 is turned on and held on until the overvoltage condition clears.

Foldback current limiting is provided if the output is shorted to ground. As \( V_{FB} \) drops, the buffered current threshold voltage \( I_{\text{THB}} \) is pulled down by clamp Q3 to a 1V level set by Q4 and Q6. This reduces the inductor valley current level to one sixth of its maximum value as \( V_{FB} \) approaches 0V.

Pulling the RUN/SS pin low forces the controller into its shutdown state, turning off both M1 and M2. Releasing the pin allows an internal 1.2\( \mu \)A current source to charge up an external soft-start capacitor, \( C_{SS} \). When this voltage reaches 1.5V, the controller turns on and begins switching, but with the \( I_{\text{TH}} \) voltage clamped at approximately 0.6V below the RUN/SS voltage. As \( C_{SS} \) continues to charge, the soft-start current limit is removed.

**INTV\text{CC}/EXTV\text{CC} Power**

Power for the top and bottom MOSFET drivers and most of the internal controller circuitry is derived from the INTV\text{CC} pin. The top MOSFET driver is powered from a floating bootstrap capacitor \( C_{B} \). This capacitor is recharged from INTV\text{CC} through an external Schottky diode, \( D_{B} \), when the top MOSFET is turned off. When the EXT\text{CC} pin is grounded, an internal 5V low dropout regulator supplies the INTV\text{CC} power from \( V_{IN} \). If EXT\text{CC} rises above 4.7V, the internal regulator is turned off, and an internal switch connects EXT\text{CC} to INTV\text{CC}. This allows a high efficiency source connected to EXT\text{CC}, such as an external 5V supply or a secondary output from the converter, to provide the INTV\text{CC} power. Voltages up to 7V can be applied to EXT\text{CC} for additional gate drive. If the input voltage is low and INTV\text{CC} drops below 3.5V, undervoltage lockout circuitry prevents the power switches from turning on.
The basic LTC3610 application circuit is shown on the front page of this data sheet. External component selection is primarily determined by the maximum load current. The LTC3610 uses the on-resistance of the synchronous power MOSFET for determining the inductor current. The desired amount of ripple current and operating frequency also determines the inductor value. Finally, Cin is selected for its ability to handle the large RMS current into the converter and Cout is chosen with low enough ESR to meet the output voltage ripple and transient specification.

**VON and PGOOD**

The LTC3610 has an open-drain PGOOD output that indicates when the output voltage is within ±10% of the regulation point. The LTC3610 also has a VON pin that allows the on-time to be adjusted. Tying the VON pin high results in lower values for Ron which is useful in high VOUT applications. The VON pin also provides a means to adjust the on-time to maintain constant frequency operation in applications where VOUT changes and to correct minor frequency shifts with changes in load current.

**VRNG Pin and ILIMIT Adjust**

The VRNG pin is used to adjust the maximum inductor valley current, which in turn determines the maximum average output current that the LTC3610 can deliver. The maximum output current is given by:

\[
I_{\text{OUT(MAX)}} = I_{\text{VALLEY(MAX)}} + \frac{1}{2} \Delta I_L
\]

The IVALLEY(MAX) is shown in the figure “Maximum Valley Current Limit vs VRNG Voltage” in the Typical Performance Characteristics.

An external resistor divider from INTVCC can be used to set the voltage on the VRNG pin from 0.5V to 1V, or it can be simply tied to ground force a default value equivalent to 0.7V. When setting current limit, ensure that the junction temperature does not exceed the maximum rating of 125°C. Do not float the VRNG pin.

**Operating Frequency**

The choice of operating frequency is a trade-off between efficiency and component size. Low frequency operation improves efficiency by reducing MOSFET switching losses but requires larger inductance and/or capacitance in order to maintain low output ripple voltage.

The operating frequency of LTC3610 applications is determined implicitly by the one-shot timer that controls the on-time tON of the top MOSFET switch. The on-time is set by the current into the ION pin and the voltage at the VON pin according to:

\[
t_{\text{ON}} = \frac{V_{\text{ON}}}{I_{\text{ON}}} (10\text{pF})
\]

Tying a resistor, Ron, from VIN to the ION pin yields an on-time inversely proportional to VIN. The current out of the ION pin is:

\[
I_{\text{ON}} = \frac{V_{\text{IN}}}{R_{\text{ON}}}
\]

For a step-down converter, this results in approximately constant frequency operation as the input supply varies:

\[
f = \frac{V_{\text{OUT}}}{V_{\text{VON}} R_{\text{ON}} (10\text{pF})} \left[ \text{Hz} \right]
\]

To hold frequency constant during output voltage changes, tie the VON pin to VOUT or to a resistive divider from VOUT when VOUT > 2.4V. The VON pin has internal clamps that limit its input to the one-shot timer. If the pin is tied below 0.7V, the input to the one-shot is clamped at 0.7V. Similarly, if the pin is tied above 2.4V, the input is clamped at 2.4V. In high VOUT applications, tying VON to INTVCC so that the comparator input is 2.4V results in a lower value for RON. Figures 1a and 1b show how RON relates to switching frequency for several common output voltages.
Because the voltage at the $I_{ON}$ pin is about 0.7V, the current into this pin is not exactly inversely proportional to $V_{IN}$, especially in applications with lower input voltages. To correct for this error, an additional resistor $R_{ON2}$ connected from the $I_{ON}$ pin to the 5V INTVCC supply will further stabilize the frequency.

$$R_{ON2} = \frac{5V}{0.7V} R_{ON}$$

Changes in the load current magnitude will also cause frequency shift. Parasitic resistance in the MOSFET switches and inductor reduce the effective voltage across the inductance, resulting in increased duty cycle as the load current increases. By lengthening the on-time slightly as current increases, constant frequency operation can be maintained. This is accomplished with a resistive divider from the $I_{TH}$ pin to the $V_{ON}$ pin and $V_{OUT}$. The values required will depend on the parasitic resistances in the specific application. A good starting point is to feed about 25% of the voltage change at the $I_{TH}$ pin to the $V_{ON}$ pin as shown in Figure 2a. Place capacitance on the $V_{ON}$ pin to filter out the $I_{TH}$ variations at the switching frequency. The resistor load on $I_{TH}$ reduces the DC gain of the error amp and degrades load regulation, which can be avoided by using the PNP emitter follower of Figure 2b.

### Minimum Off-Time and Dropout Operation

The minimum off-time, $t_{OFF(MIN)}$, is the smallest amount of time that the LTC3610 is capable of turning on the bottom MOSFET, tripping the current comparator and turning the MOSFET back off. This time is generally about 250ns. The minimum off-time limit imposes a maximum duty cycle of $t_{ON}/(t_{ON} + t_{OFF(MIN)})$. If the maximum duty cycle is reached, due to a dropping input voltage for example, then the output will drop out of regulation. The minimum input voltage to avoid dropout is:

$$V_{IN(MIN)} = V_{OUT} \frac{t_{ON} + t_{OFF(MIN)}}{t_{ON}}$$

A plot of maximum duty cycle vs frequency is shown in Figure 3.

### Setting the Output Voltage

The LTC3611 develops a 0.6V reference voltage between the feedback pin, $V_{FB}$, and the signal ground as shown in Figure 6. The output voltage is set by a resistive divider according to the following formula:

$$V_{OUT} = 0.6V \left(1 + \frac{R2}{R1}\right)$$

To improve the frequency response, a feedforward capacitor C1 may also be used. Great care should be taken to route the $V_{FB}$ line away from noise sources, such as the inductor or the SW trace.
LTC3610

APPLICATIONS INFORMATION

Inductor Selection
Given the desired input and output voltages, the inductor value and operating frequency determine the ripple current:

\[ \Delta I_L = \left( \frac{V_{OUT}}{f L} \right) \left( 1 - \frac{V_{OUT}}{V_{IN}} \right) \]

Lower ripple current reduces core losses in the inductor, ESR losses in the output capacitors and output voltage ripple. Highest efficiency operation is obtained at low frequency with small ripple current. However, achieving this requires a large inductor. There is a trade-off between component size, efficiency and operating frequency.

A reasonable starting point is to choose a ripple current that is about 40% of \( I_{OUT(MAX)} \). The largest ripple current occurs at the highest \( V_{IN} \). To guarantee that ripple current does not exceed a specified maximum, the inductance should be chosen according to:

\[ L = \left( \frac{V_{OUT}}{f \Delta I_L(MAX)} \right) \left( 1 - \frac{V_{OUT}}{V_{IN(MAX)}} \right) \]

Once the value for \( L \) is known, the type of inductor must be selected. High efficiency converters generally cannot afford the core loss found in low cost powdered iron cores. A variety of inductors designed for high current, low voltage applications are available from manufacturers such as Sumida, Panasonic, Coiltronics, Coilcraft and Toko.

\( C_{IN} \) and \( C_{OUT} \) Selection
The input capacitance \( C_{IN} \) is required to filter the square wave current at the drain of the top MOSFET. Use a low ESR capacitor sized to handle the maximum RMS current.

\[ I_{RMS} = I_{OUT(MAX)} \frac{V_{OUT}}{V_{IN}} \sqrt{\frac{V_{IN}}{V_{OUT}}} - 1 \]

This formula has a maximum at \( V_{IN} = 2V_{OUT} \), where \( I_{RMS} = I_{OUT(MAX)}/2 \). This simple worst-case condition is commonly used for design because even significant deviations do not offer much relief. Note that ripple current ratings from capacitor manufacturers are often based on only 2000 hours of life which makes it advisable to derate the capacitor.

The selection of \( C_{OUT} \) is primarily determined by the ESR required to minimize voltage ripple and load step transients. The output ripple \( \Delta V_{OUT} \) is approximately bounded by:

\[ \Delta V_{OUT} \leq \Delta I_L \left( \frac{ESR + \frac{1}{8fC_{OUT}}}{8fC_{OUT}} \right) \]
Since $\Delta I_L$ increases with input voltage, the output ripple is highest at maximum input voltage. Typically, once the ESR requirement is satisfied, the capacitance is adequate for filtering and has the necessary RMS current rating.

Multiple capacitors placed in parallel may be needed to meet the ESR and RMS current handling requirements. Dry tantalum, special polymer, aluminum electrolytic and ceramic capacitors are all available in surface mount packages. Special polymer capacitors offer very low ESR but have lower capacitance density than other types. Tantalum capacitors have the highest capacitance density but it is important to only use types that have been surge tested for use in switching power supplies. Aluminum electrolytic capacitors have significantly higher ESR, but can be used in cost-sensitive applications providing that consideration is given to ripple current ratings and long-term reliability. Ceramic capacitors have excellent low ESR characteristics but can have a high voltage coefficient and audible piezoelectric effects. The high Q of ceramic capacitors with trace inductance can also lead to significant ringing. When used as input capacitors, care must be taken to ensure that ringing from inrush currents and switching does not pose an overvoltage hazard to the power switches and controller. To dampen input voltage transients, add a small 5µF to 50µF aluminum electrolytic capacitor with an ESR in the range of 0.5Ω to 2Ω. High performance through-hole capacitors may also be used, but an additional ceramic capacitor in parallel is recommended to reduce the effect of their lead inductance.

**Top MOSFET Driver Supply (C_B, D_B)**

An external bootstrap capacitor, C_B, connected to the BOOST pin supplies the gate drive voltage for the topside MOSFET. This capacitor is charged through diode D_B from INTV_CC when the switch node is low. When the top MOSFET turns on, the switch node rises to V_IN and the BOOST pin rises to approximately V_IN + INTV_CC. The boost capacitor needs to store about 100 times the gate charge required by the top MOSFET. In most applications an 0.1µF to 0.47µF X5R or X7R dielectric capacitor is adequate.

**Discontinuous Mode Operation and FCB Pin**

The FCB pin determines whether the bottom MOSFET remains on when current reverses in the inductor. Tying this pin above its 0.6V threshold enables discontinuous operation where the bottom MOSFET turns off when inductor current reverses. The load current at which current reverses and discontinuous operation begins depends on the amplitude of the inductor ripple current and will vary with changes in V_IN. Tying the FCB pin below the 0.6V threshold forces continuous synchronous operation, allowing current to reverse at light loads and maintaining high frequency operation.

In addition to providing a logic input to force continuous operation, the FCB pin provides a means to maintain a flyback winding output when the primary is operating in discontinuous mode. The secondary output V_OUT2 is normally set as shown in Figure 4 by the turns ratio N of the transformer. However, if the controller goes into discontinuous mode and halts switching due to a light primary load current, then V_OUT2 will droop. An external resistor divider from V_OUT2 to the FCB pin sets a minimum voltage V_OUT2(MIN) below which continuous operation is forced until V_OUT2 has risen above its minimum:

$$V_{OUT2(MIN)} = 0.6V \left(1 + \frac{R_4}{R_3}\right)$$

**Fault Conditions: Current Limit and Foldback**

The LTC3610 has a current mode controller which inherently limits the cycle-by-cycle inductor current not only in steady state operation but also in transient. To further limit current in the event of a short circuit to ground, the LTC3610 includes foldback current limiting. If the output falls by more than 25%, then the maximum sense voltage is progressively lowered to about one sixth of its full value.
INTVCC Regulator and EXTVCC Connection

An internal P-channel low dropout regulator produces the 5V supply that powers the drivers and internal circuitry within the LTC3610. The INTVCC pin can supply up to 50mA RMS and must be bypassed to ground with a minimum of 4.7µF tantalum or ceramic capacitor. Good bypassing is necessary to supply the high transient currents required by the MOSFET gate drivers.

The EXTVCC pin can be used to provide MOSFET gate drive and control power from the output or another external source during normal operation. Whenever the EXTVCC pin is above 4.7V the internal 5V regulator is shut off and an internal 50mA P-channel switch connects the EXTVCC pin to INTVCC. INTVCC power is supplied from EXTVCC until this pin drops below 4.5V. Do not apply more than 7V to the EXTVCC pin and ensure that EXTVCC ≤ VIN. The following list summarizes the possible connections for EXTVCC:

1. EXTVCC grounded. INTVCC is always powered from the internal 5V regulator.

2. EXTVCC connected to an external supply. A high efficiency supply compatible with the MOSFET gate drive requirements (typically 5V) can improve overall efficiency.

3. EXTVCC connected to an output derived boost network. The low voltage output can be boosted using a charge pump or flyback winding to greater than 4.7V. The system will start-up using the internal linear regulator until the boosted output supply is available.

Soft-Start and Latchoff with the RUN/SS Pin

The RUN/SS pin provides a means to shut down the LTC3610 as well as a timer for soft-start and overcurrent latchoff. Pulling the RUN/SS pin below 0.8V puts the LTC3610 into a low quiescent current shutdown (IQ < 30µA). Releasing the pin allows an internal 1.2µA current source to charge up the external timing capacitor CSS. If RUN/SS has been pulled all the way to ground, there is a delay before starting of about:

\[ t_{\text{DELAY}} = \frac{1.5V}{1.2\mu A} C_{\text{SS}} = (1.3s/\mu F) C_{\text{SS}} \]
APPLICATIONS INFORMATION

When the voltage on RUN/SS reaches 1.5V, the LTC3610 begins operating with a clamp on I\textsubscript{TH} of approximately 0.9V. As the RUN/SS voltage rises to 3V, the clamp on I\textsubscript{TH} is raised until its full 2.4V range is available. This takes an additional 1.3s/\mu F during which the load current is folded back until the output reaches 75% of its final value.

After the controller has been started and given adequate time to charge up the output capacitor, C\textsubscript{SS} is used as a short-circuit timer. After the RUN/SS pin charges above 4V, if the output voltage falls below 75% of its regulated value, then a short-circuit fault is assumed. A 1.8\mu A current then begins discharging C\textsubscript{SS}. If the fault condition persists until the RUN/SS pin drops to 3.5V, then the controller turns off both power MOSFETs, shutting down the converter permanently. The RUN/SS pin must be actively pulled down to ground in order to restart operation.

The overcurrent protection timer requires that the soft-start timing capacitor, C\textsubscript{SS}, be made large enough to guarantee that the output is in regulation by the time C\textsubscript{SS} has reached the 4V threshold. In general, this will depend upon the size of the output capacitance, output voltage and load current characteristic. A minimum soft-start capacitor can be estimated from:

$$C_{SS} > C_{OUT} \frac{V_{OUT}}{R_{SENSE}} (10^{-4} [F/V \cdot s])$$

Generally 0.1\mu F is more than sufficient.

Overcurrent latchoff operation is not always needed or desired. Load current is already limited during a short-circuit by the current foldback circuitry and latchoff operation can prove annoying during troubleshooting. The feature can be overridden by adding a pull-up current greater than 5\mu A to the RUN/SS pin. The additional current prevents the discharge of C\textsubscript{SS} during a fault and also shortens the soft-start period. Using a resistor to V\textsubscript{IN} as shown in Figure 5a is simple, but slightly increases shutdown current. Connecting a resistor to INTV\textsubscript{CC} as shown in Figure 5b eliminates the additional shutdown current, but requires a diode to isolate C\textsubscript{SS}. Any pull-up network must be able to pull RUN/SS above the 4.2V maximum threshold of the latchoff circuit and overcome the 4\mu A maximum discharge current.

Efficiency Considerations

The percent efficiency of a switching regulator is equal to the output power divided by the input power times 100%. It is often useful to analyze individual losses to determine what is limiting the efficiency and which change would produce the most improvement. Although all dissipative elements in the circuit produce losses, four main sources account for most of the losses in LTC3610 circuits:

1. DC I\textsuperscript{2}R losses. These arise from the resistance of the internal resistance of the MOSFETs, inductor and PC board traces and cause the efficiency to drop at high output currents. In continuous mode the average output current flows through L, but is chopped between the top and bottom MOSFETs. The DC I\textsuperscript{2}R loss for one MOSFET can simply be determined by \([R_{DS(ON)} + R_L] \cdot I_O]\).

2. Transition loss. This loss arises from the brief amount of time the top MOSFET spends in the saturated region during switch node transitions. It depends upon the input voltage, load current, driver strength and MOSFET capacitance, among other factors. The loss is significant at input voltages above 20V and can be estimated from:

$$\text{Transition Loss} \equiv (1.7A^{-1}) \frac{V_{IN}}{V_{OUT}} \text{C}_{RSS} f$$

3. INTV\textsubscript{CC} current. This is the sum of the MOSFET driver and control currents. This loss can be reduced by supplying INTV\textsubscript{CC} current through the EXTV\textsubscript{CC} pin from a high efficiency source, such as an output derived boost network or alternate supply if available.
4. C\textsubscript{IN} loss. The input capacitor has the difficult job of filtering the large RMS input current to the regulator. It must have a very low ESR to minimize the AC I\textsuperscript{2}R loss and sufficient capacitance to prevent the RMS current from causing additional upstream losses in fuses or batteries.

Other losses, including C\textsubscript{OUT} ESR loss, Schottky diode D\textsubscript{1} conduction loss during dead time and inductor core loss generally account for less than 2% additional loss.

When making adjustments to improve efficiency, the input current is the best indicator of changes in efficiency. If you make a change and the input current decreases, then the efficiency has increased. If there is no change in input current, then there is no change in efficiency.

Checking Transient Response

The regulator loop response can be checked by looking at the load transient response. Switching regulators take several cycles to respond to a step in load current. When a load step occurs, V\textsubscript{OUT} immediately shifts by an amount equal to \(\Delta\text{LOAD}\) (ESR), where ESR is the effective series resistance of C\textsubscript{OUT}. \(\Delta\text{LOAD}\) also begins to charge or discharge C\textsubscript{OUT} generating a feedback error signal used by the regulator to return V\textsubscript{OUT} to its steady-state value. During this recovery time, V\textsubscript{OUT} can be monitored for overshoot or ringing that would indicate a stability problem. The I\textsubscript{TH} pin external components shown in Figure 6 will provide adequate compensation for most applications. For a detailed explanation of switching control loop theory see Application Note 76.

Design Example

As a design example, take a supply with the following specifications: \(V\textsubscript{IN} = 5\text{V}\) to 24\text{V} (12\text{V} nominal), \(V\textsubscript{OUT} = 2.5\text{V} \pm 5\%\), \(I\text{OUT(MAX)} = 12\text{A}, f = 550\text{kHz}\). First, calculate the timing resistor with \(V\text{ON} = V\text{OUT}\):

\[
R\text{ON} = \frac{1}{(550\text{kHz})(10\text{pF})} = 182k
\]

and choose the inductor for about 40% ripple current at the maximum \(V\text{IN}\):

\[
L = \frac{2.5\text{V}}{(550\text{kHz})(0.4)(12\text{A})(1- \frac{2.5\text{V}}{28\text{V}})} = 0.86\mu\text{H}
\]

Selecting a standard value of 0.82\(\mu\text{H}\) results in a maximum ripple current of:

\[
\Delta I\text{L} = \frac{2.5\text{V}}{(550\text{kHz})(0.82\mu\text{H})} = 4.4\text{A}
\]

Next, set up V\textsubscript{RING} voltage and check the I\textsubscript{LIMIT}. Tying V\textsubscript{RING} to 0.5\text{V} will set the typical current limit to 16\text{A}, and tying V\textsubscript{RING} to GND will result in a typical current around 19\text{A}. C\textsubscript{IN} is chosen for an RMS current rating of about 5\text{A} at 85°C. The output capacitors are chosen for a low ESR of 0.013\(\Omega\) to minimize output voltage changes due to inductor ripple current and load steps. The ripple voltage will be only:

\[
\Delta V\text{OUT(ripple)} = \Delta I\text{L(MAX)} (ESR) = (4.4\text{A})(0.013\Omega) = 57\text{mV}
\]

However, a 0\text{A} to 10\text{A} load step will cause an output change of up to:

\[
\Delta V\text{OUT(step)} = \Delta I\text{LOAD} (ESR) = (10\text{A})(0.013\Omega) = 130\text{mV}
\]

An optional 22\(\mu\text{F}\) ceramic output capacitor is included to minimize the effect of ESL in the output ripple. The complete circuit is shown in Figure 6.

How to Reduce SW Ringing

As with any switching regulator, there will be voltage ringing on the SW node, especially for high input voltages. The ringing amplitude and duration is dependent on the switching speed (gate drive), layout (parasitic inductance) and MOSFET output capacitance. This ringing contributes to the overall EMI, noise and high frequency ripple. One way to reduce ringing is to optimize layout. A good layout minimizes parasitic inductance. Adding RC snubbers from SW to GND is also an effective way to reduce ringing. Finally, adding a resistor in series with the BOOST pin will slow down the MOSFET turn-on slew rate to dampen ringing, but at the cost of reduced efficiency. Note that since the IC is buffered from the high frequency transients by PCB and bondwire inductances, the ringing by itself is normally not a concern for controller reliability.
**Applications Information**

**Figure 6. Design Example: 5V to 24V Input to 2.5V/12A at 550kHz**

**PC Board Layout Checklist**

When laying out a PC board follow one of the two suggested approaches. The simple PC board layout requires a dedicated ground plane layer. Also, for higher currents, a multilayer board is recommended to help with heat sinking of power components.

- The ground plane layer should not have any traces and it should be as close as possible to the layer with the LTC3610.

- Place $C_{\text{IN}}$ and $C_{\text{OUT}}$ all in one compact area, close to the LTC3610. It may help to have some components on the bottom side of the board.

- Keep small-signal components close to the LTC3610.

- Ground connections (including LTC3610 SGND and PGND) should be made through immediate vias to the ground plane. Use several larger vias for power components.

- Use a compact plane for the switch node (SW) to improve cooling of the MOSFETs and to keep EMI down.

- Use planes for $V_{\text{IN}}$ and $V_{\text{OUT}}$ to maintain good voltage filtering and to keep power losses low.

- Flood all unused areas on all layers with copper. Flooding with copper reduces the temperature rise of power components. Connect these copper areas to any DC net ($V_{\text{IN}}$, $V_{\text{OUT}}$, GND or to any other DC rail in your system).
When laying out a printed circuit board without a ground plane, use the following checklist to ensure proper operation of the controller. These items are also illustrated in Figure 7.

- Segregate the signal and power grounds. All small-signal components should return to the SGND pin at one point, which is then tied to the PGND pin.
- Connect the input capacitor(s), \( C_{IN} \), close to the IC. This capacitor carries the MOSFET AC current.
- Keep the high \( dV/dt \) SW, BOOST and TG nodes away from sensitive small-signal nodes.
- Connect the INTVCC decoupling capacitor, \( C_{VCC} \), closely to the INTVCC and PGND pins.
- Connect the top driver boost capacitor, \( C_B \), closely to the BOOST and SW pins.
- Connect the \( V_{IN} \) pin decoupling capacitor, \( C_F \), closely to the \( V_{IN} \) and PGND pins.
TYPICAL APPLICATIONS

3.3V Input to 1.5V/12A at 750kHz

Ccs: TAIYO YUDEN TMK432BJ106MM
Ccs: SANYO 10TPE220ML
LT: TDK TDY1040-36M
CS: TAIYO YUDEN JMK316BJ226ML-T

3.3V Input to 1.5V/12A at 750kHz

Ccs: TAIYO YUDEN TMK432BJ106MM
Ccs: SANYO 10TPE220ML
LT: TDK TDY1040-36M
CS: TAIYO YUDEN JMK316BJ226ML-T

Downloaded from Arrow.com.
5V to 24V Input to 1.2V/12A at 550kHz

VOUT
1.2V AT
12A

GND

COUT1
220µF
2×
C5
22µF
6.3V

L1
0.52µH

CIN
10µF
25V
3×
C6
10µF
35V

C5: TAIYO YUDEN JMK316BJ226ML-T
CIN: TAIYO YUDEN TMK432BJ106MM
COUT1: SANYO 10TPE220ML
L1: WURTH 744310055

SGND 48
SGND 47
SGND 46
SGND 45
EXTVCC 44
VFB 43
SGND 42
ION 41
SGND 40
FCB 39
ITH 38
VRNG 37
PGOOD 36
VON 35
SGND 34

PVIN 17
PVIN 18
PVIN 19
PVIN 20
PVIN 21
PVIN 22
PVIN 23
PVIN 24
PVIN 25
PVIN 26
PVIN 27
PVIN 28
PVIN 29
PVIN 30
PVIN 31
PVIN 32
PVIN 33

PGND 64
PGND 63
PGND 62
PGND 61
PGND 60
PGND 59
PGND 58
PGND 57
PGND 56
PGND 55
PGND 54
PGND 53
SVIN 52
SVIN 51
SGND 50
SGND 49

PGND1
PGND2
PGND3
SW 4
SW 3
SW 2
SW 1
PVIN 12
PVIN 11
PVIN 10
PVIN 9
PVIN 8
PVIN 7
PVIN 6
PVIN 5
PVIN 4
PVIN 3
PVIN 2
PVIN 1

CON 0.01µF
C4 0.01µF
C2

DB CMDSH-3
CSS
0.1µF

C3 22µF
25V

 RSS1 510k

R1 30k
1%

R2 301k
1%

RON

RPG1 100k

R5 31.84k

CC1 470pF
CC2 100pF

CVON (OPTIONAL)
RVON

CVCC 4.7µF
6.3V

CF 0.1µF
25V

RF1 1/uni03A9

VIN

5V TO 24V

SW
BOOST
INTVCC

CB1 0.22µF

Downloaded from Arrow.com.
TYPICAL APPLICATIONS

5V to 24V Input to 1.8V/12A All Ceramic 1MHz

LTC3610

VOUT 1.8V AT 12A

VOUT 1.8V AT 12A

LTC3610

C5: TAIYO YUDEN JMK316BJ226ML-T

COUT: TAIYO YUDEN JMK325BJ107MY

L1: TOKIN MPLC0730

CIN: 10µF 25V

C5: 22µF 6.3V

COUT: 100µF

2×

C5

1.8V TO 24V

10µF

25V

3×

CIN

0.47µH

L1

PGND

PGND

PGND

PGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

VCC

VCC

VCC

VCC

EXTVCC

EXTVCC

EXTVCC

EXTVCC

VFB

VFB

VFB

VFB

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

SGND

C4

0.1µF 25V

CF

0.1µF

CVCC

4.7µF 6.3V

CON

0.01µF

C4

0.01µF

C1

C2

R5

18.7k

CC1

560pF

CC2

100pF

CVON

(OPTIONAL)

RVON

SW

BOOST

INTVCC

CB1

0.22µF

Downloaded from Arrow.com.
WP Package
64-Lead QFN Multipad (9mm × 9mm)
(Reference LTC DWG # 05-08-1812 Rev A)

NOTE:
1. DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5M-1994
2. ALL DIMENSIONS ARE IN MILLIMETERS, ANGLES ARE IN DEGREES (°)
3. N IS THE TOTAL NUMBER OF TERMINALS
4. THE LOCATION OF THE TERMINAL # IDENTIFIER AND TERMINAL NUMBERING
   CONVENTION CONFORMS TO JEDC PUBLICATION 95 SPP-002
5. DIMENSION b APPLIES TO METALLIZED TERMINAL AND IS MEASURED BETWEEN 0.15mm AND 0.30mm FROM THE TERMINAL TIP.
6. COPLANARITY APPLIES TO THE TERMINALS AND ALL OTHER SURFACE METALLIZATION

<table>
<thead>
<tr>
<th>SYMBOL</th>
<th>TOLERANCE</th>
</tr>
</thead>
<tbody>
<tr>
<td>a</td>
<td>0.15</td>
</tr>
<tr>
<td>b</td>
<td>0.10</td>
</tr>
<tr>
<td>c</td>
<td>0.10</td>
</tr>
</tbody>
</table>
### REVISION HISTORY

(Revision history begins at Rev F)

<table>
<thead>
<tr>
<th>REV</th>
<th>DATE</th>
<th>DESCRIPTION</th>
<th>PAGE NUMBER</th>
</tr>
</thead>
<tbody>
<tr>
<td>F</td>
<td>07/10</td>
<td>I-grade part added. Reflected throughout the data sheet.</td>
<td>1 to 24</td>
</tr>
</tbody>
</table>
14V to 24V Input to 12V/5A at 500kHz

**RELATED PARTS**

<table>
<thead>
<tr>
<th>PART NUMBER</th>
<th>DESCRIPTION</th>
<th>COMMENTS</th>
</tr>
</thead>
<tbody>
<tr>
<td>LTC1778</td>
<td>No R_SENSE Current Mode Synchronous Step-Down Controller</td>
<td>Up to 97% Efficiency, ( V_{IN} ): 4V to 36V, ( 0.8V \leq V_{OUT} \leq (0.9)(V_{IN}) ), I_OUT Up to 20A</td>
</tr>
<tr>
<td>LTC3411</td>
<td>1.25A (I_OUT), 4MHz, Synchronous Step-Down DC/DC Converter</td>
<td>95% Efficiency, ( V_{IN} ): 2.5V to 5.5V, ( V_{OUT} = 0.8V, I_O = 60\mu A, ISD &lt;1\mu A, MS Package</td>
</tr>
<tr>
<td>LTC3412</td>
<td>2.5A (I_OUT), 4MHz Synchronous Step-Down DC/DC Converter</td>
<td>95% Efficiency, ( V_{IN} ): 2.5V to 5.5V, ( V_{OUT(MIN)} = 0.8V, I_O = 60\mu A, ISD &lt;1\mu A, TSSOP16E</td>
</tr>
<tr>
<td>LTC3414</td>
<td>4A (I_OUT), 4MHz, Synchronous Step-Down DC/DC Converter</td>
<td>95% Efficiency, ( V_{IN} ): 2.25V to 5.5V, ( V_{OUT(MIN)} = 0.8V, I_O = 64\mu A, ISD &lt;1\mu A, TSSOP20E Package</td>
</tr>
<tr>
<td>LTC3418</td>
<td>8A (I_OUT), 4MHz, Synchronous Step-Down DC/DC Converter</td>
<td>95% Efficiency, ( V_{IN} ): 2.25V to 5.5V, ( V_{OUT(MIN)} = 0.8V, Thermally Enhanced 38-Lead QFN Package</td>
</tr>
<tr>
<td>LTC3770</td>
<td>Fast, No R_SENSE Step-Down Synchronous Controller with Margining, Tracking, PLL</td>
<td>±0.67% 0.6V Reference Voltage; Programmable Margining; True Current Mode; 4V \leq V_{IN} \leq 32V</td>
</tr>
<tr>
<td>LTC3778</td>
<td>Low V_OUT No R_SENSE Synchronous Step-Down Controller</td>
<td>0.6V \leq V_{OUT} \leq (0.9)(V_{IN}), 4V \leq V_{IN} \leq 36V, I_OUT Up to 20A</td>
</tr>
<tr>
<td>LT3800</td>
<td>60V Synchronous Step-Down Controller</td>
<td>Current Mode, Output Slew Rate Control</td>
</tr>
<tr>
<td>LTM4600HV</td>
<td>10A Complete Switch Mode Power Supply</td>
<td>92% Efficiency, ( V_{IN} ): 4.5V to 28V, ( V_{OUT} = 0.6V ), True Current Mode Control, Ultrafast Transient Response</td>
</tr>
<tr>
<td>LTM4601HV</td>
<td>12A Complete Switch Mode Power Supply</td>
<td>92% Efficiency, ( V_{IN} ): 4.5V to 28V, ( V_{OUT} = 0.6V ), True Current Mode Control, Ultrafast Transient Response</td>
</tr>
<tr>
<td>LTM4602HV</td>
<td>6A Complete Switch Mode Power Supply</td>
<td>92% Efficiency, ( V_{IN} ): 4.5V to 28V, ( V_{OUT} = 0.6V ), True Current Mode Control, Ultrafast Transient Response</td>
</tr>
<tr>
<td>LTM4603HV</td>
<td>6A Complete Switch Mode Power Supply</td>
<td>93% Efficiency, ( V_{IN} ): 4.5V to 28V, with PLL, Output Tracking and Margining</td>
</tr>
</tbody>
</table>